

DOCKET NO: 247866US2S



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
AKIRA HOKAZONO, ET AL. : EXAMINER: MAGEE, T.
SERIAL NO: 10/759,205 :
RCE FILED: HERewith : GROUP ART UNIT: 2811
FOR: SEMICONDUCTOR DEVICE :
HAVING METAL SILICIDE FILMS
FORMED ON SOURCE AND DRAIN
REGIONS AND METHOD FOR
MANUFACTURING THE SAME

AMENDMENT FILED CONCURRENTLY WITH REQUEST FOR CONTINUED
EXAMINATION UNDER 37 C.F.R. § 1.114

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated June 29, 2005, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.